On the Evaluation of Mechanical Properties and Ballistic Performance of Two Variants of Boron Carbide

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Abstract

A comparative study on the microstructure, rate-dependent compressive behavior, and ballistic performance of commercially available pressureless sintered boron carbide-titanium diboride (material Z) and hot-pressed boron carbide (material S) was conducted. Under quasi-static compression at rates of 1.4 to $1.6 \times 10^{-4} \text{ s}^{-1}$, the strength was found to be 3.07 ± 0.11 GPa for Z and 4.72 ± 0.14 GPa for S. At dynamic strain rates ranging from 185 to 1152 s⁻¹, the compressive strength ranged from 3.56 to 4.07 GPa for material Z and 5.24 to 5.97 GPa for material S. Depth of penetration testing was performed using 7.62 mm AP M2 projectiles. The normalized ballistic efficiency of the two materials were found to be comparable at 932 m/s, while material S was superior to material Z at an impact velocity of 1078 m/s. Based on post-mortem SEM analysis of ballistic tile fragments, the inferior mechanical properties and ballistic performance of material Z are attributed to an uneven distribution of silicon impurities and a significant level of porosity.

Keywords: boron carbide, fracture, digital image correlation, rate-dependent uniaxial compression, ballistic, ceramic, depth of penetration

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1. Introduction

Boron carbide (B₄C) is attractive as a structural material due to its low density $(2.52 \text{ g/cm}^3)[1]$, high compressive strength (~ 3 to 5 GPa)[2, 3], high hardness (~ 25 to 30 GPa)[4], and high Young's modulus (~ 450 to 550 GPa)[5]. An

- ⁵ important application for boron carbide is in the field of protective equipment, where it is utilized as the strike face material in composite-based personnel and vehicle armour systems. However, wider application of boron carbide has largely been limited by its low fracture toughness ($K_{1c} = 2.7$ to $3.6 \text{ MPa}\sqrt{m}[4, 6]$) and the difficulties associated with sintering boron carbide to high densities[7, 8].
- As a result, much research attention has been focused on incorporating additives to both aid in the densification of monolithic $B_4C[9, 10, 11, 12]$, as well as to form composite B_4C materials with improved properties[13, 14, 15]. In particular, boron carbide-titanium diboride (B_4C -TiB₂) composites have been found to be a promising alternative material due to their excellent mechanical
- ¹⁵ properties [16, 17].

B₄C-TiB₂ composites, which have been fabricated from B₄C and TiB₂ powders [18, 19] or through in-situ reactions with other additives[20, 21, 22], consist of a B₄C matrix reinforced by titanium diboride (TiB₂) particles. The introduction of a secondary TiB₂ phase into B₄C has been shown to improve sinterability[20, 22], while also enhancing a range of mechanical properties[16, 17, 18, 23]. Many studies have focused on the increased flexural strength and fracture toughness of B₄C-TiB₂ composites in comparison to monolithic B₄C[16, 24, 25]. This toughening effect has been attributed to a combination of crack bridging and deflection due to the reinforcing TiB₂ particles[20, 24,

²⁵ 26], as well as microcracking at the weak boundaries between B₄C and TiB₂ particles[15, 18, 25]. Others have observed increased elastic modulus[15, 17] with increasing TiB₂ content. More recently, Yang et al.[23] found an overall improvement in the mechanical properties of Si/B co-doped B₄C reinforced with TiB₂. These studies have established B₄C-TiB₂ as a viable alternative structural material to B₄C based on its mechanical properties.

Beyond an understanding of their quasi-static mechanical properties, research on the dynamic response and direct ballistic testing of ceramics are also needed for the development of improved impact models and protection materials. To this end, much work has been directed at understanding the

- ³⁵ behavior of monolithic B_4C under dynamic loading conditions. Using the split-Hopkinson pressure bar (SHPB) to reach strain rates of 10^2 to 10^3 s⁻¹, Paliwal and Ramesh[2] and Swab et al.[3] investigated the rate-dependence of compressive strength in $B_4C[2, 3]$. Farbaniec et al.[27] and Hogan et al.[28] explored the effects of microstructural defects on failure mechanisms in boron carbide
- ⁴⁰ under dynamic uniaxial compression. The SHPB has also been extended to study the fracture and fragmentation behavior of boron carbide under biaxial confinement in compression[29, 30]. In terms of ballistic testing, past studies have focused on quantifying the ballistic resistance of $B_4C[31, 32, 33]$, compared the performance of B_4C to other armor ceramics[34, 35], studied the fracture
- ⁴⁵ behavior of B₄C under impact loading[36, 37, 38, 39, 40], and explored the effects of different manufacturing techniques on B₄C ballistic performance[41, 42]. However, until recently, there has been relatively little research on the dynamic behavior and failure of B₄C-TiB₂. Efforts toward filling this gap have come from Gao and co-workers, who studied the rate-dependent compressive and
- tensile behavior[43], impact response[44], and shock response[45, 46] of B₄C-TiB₂. Using the data generated from these studies, Gao et al.[47] established Johnson-Holmquist II[48] model parameters for B₄C-TiB₂. In general, more work is needed to understand the dynamic failure and ballistic performance of B₄C-TiB₂ composites.
- In the present work, we compare the rate-dependent compressive behavior and ballistic performance of a B_4C -Ti B_2 composite against a monolithic B_4C ceramic. Uniaxial compression testing is coupled with ultra-high-speed imaging and digital image correlation to visualize fracture behavior and obtain quantitative stress-strain information across a range of strain rates. Depth of penetration
- tests using 7.62 mm AP M2 projectiles are conducted with in-situ ultra-highspeed imaging to evaluate the ballistic performance of the materials. In addition,

we perform post-mortem analysis on the targets and microscopic characterization on the ballistic fragments to gain insights into the failure characteristics of the two variants of boron carbide. In the discussion, the microstructural

⁶⁵ characterization and dynamic compression results are then linked to understand differences in ballistic performance between the two boron carbide-based ceramics.

2. Experimental Method

2.1. Materials

Two commercially available variants of boron carbide were studied: a pressureless sintered B₄C-TiB₂ composite, nominally material Z, and a hot-pressed monolithic B₄C ceramic, nominally material S. The materials were received as square tiles measuring 10 x 10 cm with a thickness of 6.42 ± 0.02 mm for S and 6.20 ± 0.04 mm for Z. In this section, we detail the equipment and procedure used for the microstructural characterization, mechanical testing, and the depth of penetration testing.

2.2. Scanning Electron Microscopy

Scanning electron microscopy (SEM) was used to investigate microstructural features (e.g., secondary phases) on mechanically polished surfaces of the two boron carbide variants. SEM studies were also carried out on recovered ballistic fragments of the two variants of boron carbide to identify the fracture surface characteristics and failure mechanisms. A Zeiss Sigma FESEM equipped with an energy-dispersive x-ray spectroscopy (EDS) detector was used to perform the SEM analysis in this study. The electron high tension (EHT) voltage was set at 10 kV for the Inlens detector and 20 kV for the EDS detector. The working distance was set to approximately 8.5 mm to accommodate the detecting angle of the EDS probe. The Inlens detector was used to image the microstructural features on the intact and fracture planes (field-emission), and the EDS detector was used to map out the elemental composition of the corresponding fields. The EDS map data was analyzed using the AZtec software developed by Oxford instruments. Samples were prepared using Au/Pd coatings with a thickness of ~ 8 nm to enhance conductivity. At least 15 regions across five fragments for both materials from the ballistic experiments were examined to collect representative observations.

95 2.3. X-ray Diffraction

X-ray diffraction (XRD) was used to identify the phases present in the two variants of boron carbide. This information was also used to verify the secondary phases observed under EDS mapping; contaminants picked up during the recovery process may be eliminated as constituents of the ballistic fragments. XRD spectrums were obtained using a Rigaku XRD Ultima IV system with a Cu Kα beam source, a scan rate of 1.5°/min, a step size of 0.015°, and a scanning range between 5 and 80°. The 2θ range was chosen based on typical boron carbide materials, where peaks typically occurred after 10°[49]. The apparatus was operated at 40 kV and 44 mA on a standard stage, and the 2θ-θ spectrum was obtained using SmartLab Studio-II software. Finally, the phases were matched using the JADE software with the K-α2 background signal removed.

2.3.1. Indentation Testing

Nanoindentations at loads of 50 to 100 mN were performed on both materials using a ZHN Universal Nanomechanical Tester equipped with a Berkovich diamond indenter. Calibration was done on a reference fused silica before testing. Hardness measurements were made in the quasi-continuous stiffness measurement (QCSM) mode[50] and calculated according to the ISO 14577:2015 standard[51]. Measurements were taken after a normal displacement of ~60 nm to eliminate the effect from the rounding of the indenter tip.

¹¹⁵ Vicker's hardness testing was also performed using a Wilson VH1102 microhardness tester following ASTM C1327[52]. Hardness testing was carried out on the polished surfaces of the machined compression specimens (described in Section 2.4.1), and each indent was made with a 1 kg load applied over a period of 10 s. In total, 10 measurements were made for each material.

120 2.4. Mechanical Testing

2.4.1. Quasi-static Compression

Quasi-static uniaxial compression experiments were carried out using a servohydraulic MTS 810 load frame. A detailed description and schematic of the same setup used in this study can be found in Li et al.[53]. Cuboid specimens mea-

¹²⁵ suring 3.5 mm x 2.7 mm x 2.3 mm were machined for quasi-static and dynamic compression testing. Considerations for the specimen geometry are discussed in the following subsection on Dynamic Compression. The specimens were compressed along the longest dimension (3.5 mm) with displacement control at a constant rate of 0.0035 mm/s. A U750 Promon camera with a resolution of 1280

¹³⁰ x 1024 pixels recording at 100 frames per second (FPS) was used to visualize the quasi-static compression experiments. In all experiments, the engineering stress was computed by dividing the force outputted from the load cell by the nominal cross-sectional area. DIC was applied to obtain strain information, as outlined later in Section 2.4.3, and the strain rates in the quasi-static tests were measured to range from 1.4 to 1.6 $\times 10^{-4} s^{-1}$.

2.4.2. Dynamic Compression

The dynamic uniaxial compression experiments were performed on a modified SHPB system. The theory of the SHPB system has been well documented by Song and Chen[54]. This study used the same set of bars as in Li et al.[53], where a detailed description and schematic of the setup has been provided. All bars in this setup are made of C-350 maraging steel and have a diameter of 12.7 mm. The incident and transmitted bars are 101.6 mm and 91.4 mm long, respectively. Impedance-matched tungsten carbide platens confined by Ti-6Al-4V titanium alloy were used to protect the SHPB bars from indentation by the hard ceramics. High pressure grease was applied at the interfaces between the

protection platens and specimen surfaces to reduce friction and allow free lat-

eral expansion. The stress profile for each experiment was computed using the signal from the transmitted gauge and the transmitted bar properties. As in the quasi-static compression experiments, DIC was used to make surface strain

¹⁵⁰ measurements on the sample surface during the dynamic compression experiments. A Shimadzu HPV-X2 ultra-high-speed camera with a resolution of 400 x 250 pixels was used to image the specimen surface for the application of DIC and to visualize the failure process. The frame rate was adjusted to record from 500,000 to 2,000,000 FPS depending on the strain rate, and, therefore, the time needed to drive the specimen to failure. A REL Inc. high power LED ring light provided the lighting required to image at the 200 to 1000 ns exposure times

used for these frame rates.

The same specimen geometry and dimensions were used for the dynamic compression experiments as in the quasi-static experiments. The cuboid specimen geometry has been used by other studies in the literature [27, 28, 30, 55], and past researchers have shown the viability of cuboid specimen geometries in SHPB tests [56, 57]. In addition, cuboids were chosen so that a flat surface can be imaged during mechanical testing, which enables crack speed measurements, 2D digital image correlation, and, consequently, lateral strain measurements.

- Since the strain rate has an inverse relationship with specimen thickness (i.e., 3.5 mm in our study), this small specimen size was chosen to achieve high strain rates while maintaining equilibrium and a constant strain rate[54]. Conventionally, the specimen should be much smaller than the bar to ensure force equilibrium [54]. In addition, due to the high strength of these materials, the
- 170 cross-sectional area of the specimen must also be limited to ensure that the peak stress delivered by the SHPB is greater than the compressive strength of the materials. Based on these reasons, we have chosen our specimen dimensions.

In order to access a range of dynamic strain rates, we varied the striker length (from 152 to 304 mm), as well as the dimensions and type of pulse shaper used. Tin and high density polyethylene (HDPE) pulse shapers were employed in this study because they were found to produce near triangular pulses. The pulse shaping configurations used to achieve three distinct sets of dynamic strain rates ranging from 185 to $1152 \ s^{-1}$ are summarized in Table 1. The pulse shaper diameters and thicknesses in Table 1 were chosen to achieve equilibrium at our desired strain rates. As noted by Naghdabadi et al.[58], the pulse shaper should be relatively small when testing brittle materials, and similar pulse shaper dimensions have also been investigated by Frew et al.[59] in a SPHB with the same diameter (12.7 mm). Figure 1 shows representative average strain-time profiles for material S at each of the three dynamic strain rates computed using DIC; it can be seen that the pulse shaping parameters used in this study generate constant strain rates. Uniform deformation and linear stress-strain curves were observed for all tests included in this paper. Additional details of the figure are discussed in the next section when presenting

190 2.4.3. Digital Image Correlation

DIC results.

Digital image correlation (DIC) analysis was applied to recordings of the quasi-static and dynamic experiments in this study to acquire axial strain information. Prior to testing, speckle patterns were applied to all of the compression specimens with a fine tipped air brush to facilitate correlation. VIC2D V6 (2018)

- ¹⁹⁵ was used to perform the DIC analysis in this study. The surface was discretized with a subset size of 31 x 31 pixels and a step size of 7 pixels. Correlation was carried out using the zero-normalized sum of squared differences (ZNSSD) criterion with the optimized 8 tap interpolation scheme. Strains were calculated using the engineering strain tensor, and strain rates were calculated by taking
- the slope of the linear portions of the strain-time curves. Stress-strain curves were computed by matching the average strain profile, calculated by averaging the axial strain across the entire surface, to the stress profiles generated from the quasi-static and dynamic experiments.

For a linear elastic material, the stress and surface strain profiles should nominally match up, however, poor stress equilibrium can cause localized strains to develop. As a check for stress equilibrium during dynamic experiments, we compare the stress profile against the surface strain profiles. Figure 1 shows the stress profile for a dynamic compression experiment matched up in time with the surface strain profiles computed using DIC. The average strain profile is

plotted along with strain profiles generated from the six different areas of interest (AOI) illustrated by the inset in Figure 1. The strong agreement between the strain profiles from the different regions on the specimen surface and the stress profile, which is indicative of the overall response of the specimen, shows that the specimen is in good loading equilibrium. While all considerations mentioned

²¹⁵ here are analogous to classical (strain gauge) approaches to check equilibrium in the absence of imaging information, it is also a part of the authors' methods to check for good equilibrium by checking for force balance across the sample (not shown for brevity here).

2.5. Depth of Penetration Testing

220 2.5.1. Target Configuration

The ballistic performance of the S and Z materials were evaluated using depth of penetration (DOP) experiments, a widely employed test method[34, 60, 61]. In DOP experiments, the ceramic to be assessed is usually bonded to a ductile semi-infinite backing material, and the assembly is then impacted by ²²⁵ a projectile with a velocity high enough to perforate the ceramic. The residual depth of penetration in the backing material is used to evaluate the performance of the ceramic.

In the past, DOP tests have typically been carried out using aluminum alloys[42, 62] or steel[34, 63] as the backing material. Some studies have opted to use polycarbonate as a backing material instead due to its lower ballistic resistance and acoustic impedance[64, 65, 60, 61]. Since polycarbonate is softer than aluminum and steel, the projectile will penetrate deeper into the material and produce a more sensitive measurement of DOP. When comparing materials that are expected to produce similar ballistic resistance, the increased resolution

in DOP can be useful for discriminating between test results[64]. In comparison to metals, the impedance of polycarbonate is also much closer to that of the fibre composites commonly used to back ceramic armors in practice, as noted by Carton et al.[61]. The impedance mismatch at the tile-backing interface controls the reflection of through thickness stress waves, which can lead to large tensile stresses and have a significant influence on the amount of damage sustained by

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the tile [66, 67, 68, 69].

For these reasons, we chose to use polycarbonate as a backing material for the ballistic tests in the present study. Specifically, TECANAT GF20 (20% fibre-glass reinforced) polycarbonate cylinders, each with a density of 1.33 g/cm^3 , a

- diameter of 150 mm, and a length of 300 mm, were used to form the backing. For the DOP experiments, the ceramics were tested in the form of as-received square tiles. To form the target, the ceramic tiles were bonded to the polycarbonate backing using AC-350 B1/2 adhesive manufactured by 3M. After the adhesive was spread between the ceramic tile and the polycarbonate cylinder, a force of
- ²⁵⁰ approximately 44.5 N was applied with a manual press to the combined assembly and maintained for several hours. This was done to ensure even coverage of the interface and to control the thickness of the adhesive layer. The targets were then left to cure load-free for 3 to 4 days before the DOP tests. Following the ballistic experiments, DOP measurements in the polycarbonate cylinders were
- ²⁵⁵ made using 2D X-ray imaging. Due to the slight curvature of the bullet path inside polycarbonate, the DOP was measured using the length of the bullet path instead of the horizontal depth from the polycarbonate surface.

2.5.2. Ballistic Test Setup

All ballistic experiments in this study were performed at the Defence Research and Development Canada Valcartier Research Center. To investigate ballistic resistance against armor piercing bullets, we employed 7.62 mm AP M2 projectiles with hardened steel cores for the DOP experiments in this study. A 60.96 cm long Krieger barrel with a twist rate of 1:10 was used to fire the projectiles at a muzzle to target distance of 4.038 m. The projectiles were loaded

²⁶⁵ in 0.300 Remington Ultra Mag (RUM) cartridges packed with IMR4350 rifle powder. By varying the amount of rifle powder in the cartridges, we were able to achieve two distinct bullet velocities: 932 ± 6 m/s and 1078 ± 3 m/s (bullet velocity measurement is discussed below).

A schematic of the testing setup is shown in Figure 2. As can be seen, the ceramic was unconfined, and the ceramic-polycarbonate assembly was placed in the target holder to assure perpendicularity with the barrel. The impact event was visualized in-situ using a Shimadzu HPV-X ultra-high-speed camera recording from 1,000,000 to 5,000,000 FPS. For each experiment, a total of 256 frames with a resolution of 400 x 250 pixels were captured. Mirrors were

- ²⁷⁵ positioned as shown in Figure 2 so that a single HPV-X camera can image both the front and side views of the impact. Oehler light screens, spaced 0.996 m apart, were used to detect the passage of the projectile and to trigger the lighting system. A Photron FASTCAM SA-Z, recording with a resolution of 1024 x 521 pixels at 40,000 FPS, was positioned at the side of the target to
- visualize the impact event and the ejection of fragments over a longer timescale. Both cameras were triggered using a laser system that detected the passage of the bullet. Bullet velocity measurements at multiple points along the path of the projectile were also made using the light screens and an Infinition radar sampling at 35.509 GHz, and the frames captured by the Photron FASTCAM
- ²⁸⁵ SA-Z immediately prior to impact. Measurements across the three methods were found to agree, and the velocities recorded by the Infinition radar, which were the most consistent, are reported in this study. The projectile pitch angle was also measured using the side view images from the Photron FASTCAM SA-Z, and was found to be less than or equal to 3 degrees for all tests.

290 3. Results

3.1. Material Characterization

Figure 3 shows the $\theta - 2\theta$ spectrum of material S (Figure 3 (a) and material Z (Figure 3 (b)). The XRD analysis confirms material S as monolithic boron carbide without any countable secondary phases present in the material, while ²⁹⁵ material Z contains significant amount of titanium diboride. In addition, trace amounts of iron cobalt appear at ~ 43°, which almost superimposes with the major titanium diboride peak. This could be the result of a false signal or from environmental contamination, but it is included here for completeness.

The microstructures of material S and Z are examined on mechanically polished sample surfaces, and they are shown in Figure 4 (a) and (b), respectively. In material S (Figure 4 (a)), the brighter regions correspond to the boron carbide phase, and the darker regions correspond to other phases present in the material (i.e., undissolved silicon sintering aids and carbonaceous inclusions). The compositions of other phases are confirmed in Figure 12, and these phases

account for ~20% of the total area in fig. 4 (a). In general, the secondary phases in material S can be divided into two groups based on size (i.e., in terms of major diameter): inclusions in one group has a major diameter between 0.5 and 7 μ m and inclusions in the other group has a major diameter between 20 and 100 μ m. EDS mapping was used to confirm that the smaller sized group is

comprised mainly of the undissolved silicon sintering aids, which are distributed uniformly across the material. EDS mapping also showed that the larger sized group consists of carbonaceous inclusions, and they are distributed sparsely in the material. In addition, pores are scarcely observed on the surface of material S. In contrast, dramatically different microstructure is observed for material Z

- (Figure 4 (b)), where the secondary phases (darker regions) constitute a larger percentage (~40%) of the total area in Figure 4 (b). These phases are a combination of undissolved silicon, carbonaceous inclusions, and titanium diboride, and they are confirmed in Figure 13 using EDS maps. The mixed secondary phases create a complex microstructure of material Z, where the sizes of the
- secondary phases can range from less than one micron (mainly undissolved silicon sintering aids) to several hundred microns. One particular feature we want to emphasize is that big clusters of silicon are observed in material Z, where no such phenomenon is observed in material S. In addition, pores are observed in the vicinity of the secondary phases in material Z (Figure 4 (b)), where the sur-
- faces of these phases are very rough compared to the surrounding boron carbide. These pores may arise from mechanical polishing (especially in material Z), and they are not necessarily inherent from fabrication. Hence, we have decided not

to report the initial porosity level based on these SEM investigations.

The nanoindentation and Vicker's hardness testing results are summarized ³³⁰ in Table 2. Nanoindentation was performed on both materials to identify the hardness of the constituent phases. In the SEM micrographs shown in Figure 4, boron carbide shows up as bright regions and secondary phases show up as dark regions for both materials. As an example, the yellow markings in Figure 4 represent the locations of the nanoindents within the bright regions. The samples

- were measured at a maximum force of 100 mN for the bright regions and 50 mN for the dark regions. The maximum force was reduced for the dark phases to prevent the indenter from slipping outside the smaller regions and to improve accuracy. A total of 10 and 15 indents were carried out on the bright and dark regions, respectively. For material S, the bright regions have an average
- hardness of 40.3 ± 1.4 GPa, and the dark regions have an average hardness of 34.6 ± 8.9 GPa. For material Z, the bright regions have an average hardness of 40.5 ± 1.6 GPa, and the dark regions have an average hardness of 24.6 ± 7.3 GPa. The high uncertainties of the dark regions in both materials correspond to the higher roughness and variability in distribution of the secondary phases.
- Microindentation testing showed the Vicker's hardness to be nearly identical for the two materials, at 35.4 ± 1.5 GPa for material S and 35.4 ± 2.0 GPa.

3.2. Quasi-static and Dynamic Compression

Representative stress-strain curves for both materials at one quasi-static and three dynamic strain rates are shown in Figure 5. The stress and strain profiles ³⁵⁰ were synchronized based on the time of peak stress/strain. As the specimen fails, both profiles immediately begin dropping sharply from the maximum value, which provides a clear point for matching (see S-B4C 02 in Fig 1). In total, 4 quasi-static and 15 dynamic compression experiments were performed for each material. Quasi-static strain rates ranged from 1.4 to 1.6 $\times 10^{-4}s^{-1}$ and dynamic ³⁵⁵ strain rates ranged from 185 to 1152 s^{-1} . The Young's modulus, computed by taking the slope of the stress-strain curve for each specimen, was found to be 416 ± 26 GPa for material S and 385 ± 32 GPa for material Z. The Poisson's ratio, computed by averaging the slope of the quasi-static axial-lateral strain curve for each specimen, was found to be 0.15 ± 0.01 for both materials.

- To investigate rate dependence in the compressive strength, the peak stress is plotted as a function of strain rate in Figure 6. Across all strain rates probed in this study, it can be seen that material Z exhibits significantly lower compressive strength than material S. At quasi-static strain rates, the compressive strength was found to be 3.07 ± 0.11 GPa for Z and 4.72 ± 0.14 GPa for S. Quasi-
- static failure strains were $0.83 \pm 0.05\%$ for Z and $1.16 \pm 0.07\%$ for S. Both materials showed a rate-dependent increase in peak compressive strength and failure strain at the dynamic strain rates. At the dynamic strain rates, material Z has a strength of 3.56 to 4.07 GPa and material S has a strength of 5.24 to 5.97 GPa. Dynamic failure strains ranged from 0.84\% to 1.13\% for Z and 1.11\% to
- 1.53% for S. In the current study, the approximately 20% increase in strength across the studied strain rates is consistent with the recent SHPB results by DeVries et al.[70] on coarse grain boron carbide.

3.3. Depth of Penetration Testing

The DOP testing parameters and results are summarized in Table 3. In total, 5 successful experiments were performed for material S and 6 successful experiments were performed for material Z. Figure 7 shows the DOP plotted as a function of impact velocity. The averaged reference DOP, obtained by impacting the bare polycarbonate backing at each velocity, is also included for comparison. At both impact velocities, it can be seen that material Z exhibits a greater DOP than material S. While the DOP for both materials near velocities of ~932 m/s are comparable, the difference in DOP is more apparent near velocities of ~1078 m/s. This is explored next.

Figure 8 shows four frames of the impact event captured at 2,000,000 FPS using the Shimadzu HPV-X for both materials. The first frame showing contact ³⁸⁵ between the projectile and the tile is defined as 0 µs. In the second frame, a cloud of debris consisting of projectile erosion products and ceramic fragments expands from the point of contact. Based on the high-speed videos recorded, the first radial cracks begin to propagate at $\sim 13 \,\mu s$ after impact for both materials. Such cracks are difficult to observe in static frames at this resolution, but they

can be more easily identified by comparing successive frames. As the projectile penetrates further into the tile, the radial cracks grow in thickness and are clearly visible by 25.5 μ s. Circumferential cracks, as shown later in Figure 10, are not observed to grow during the initial 30 μ s. After this time, the debris cloud expands to obscure most of the tile. By ~40 μ s, the rear surface of the projectile is no longer visible and has completely penetrated the tile.

Figure 9 shows side views of the impact event recorded at 40,000 FPS using the Photron FASTCAM SA-Z, with S on the left and Z on the right. Both materials were impacted at \sim 932 m/s. These frames are captured over a longer time scale than in Figure 8 and are included here to show the evolution of the

fragment sizes. The ejecta is initially dominated by fine, dust-like fragments in the first 100 µs after impact, as shown by the second row of frames in Figure 9. Using these high-speed videos, the velocity of the fine fragments is measured to be approximately 400 to 430 m/s. At 475 µs after impact, larger fragments begin to lift near the center of the tile. The largest fragments are slower and ejected at later time frames. This is illustrated by the large fragments near the tiles at 875 µs after impact. Since the projectile completely perforates the tile at ~40 µs after impact, much of the damage to the tile (i.e. loss of volume)

actually occurs after the projectile has fully penetrated the tile.

The impact craters for material S and Z at both impact velocities are shown in Figure 10. The fragmented tiles are held in place by the adhesive used to bond the ceramic tiles to the polycarbonate backing. At the center of the craters, the dark material is melted polycarbonate that has flowed out of the perforation from the backing. General characteristics of the craters for the two materials are similar: (1) The ceramic in the immediate area around the perforation has been

⁴¹⁵ comminuted to a fine powder; (2) Away from the perforation, the fragmented ceramic in the crater is characterized by radial and circumferential cracks that form step-like fracture surfaces; (3) Outside of the crater, radial cracks extend to the edges of the tile. Comparing the two materials, it can be seen that the craters are larger in the S tiles, with an estimated average diameter of 20.8

- \pm 4.7 mm², than in the Z tiles, with an estimated average diameter of 27.5 \pm 0.8 mm². Material S also exhibits a greater number of radial cracks and higher crack density in comparison to material Z. This is consistent with the fragmentation behavior observed during dynamic compression experiments, as material S tends to fracture into finer fragments than Z. We did not observe any
- 425 significant differences in crater characteristics between the two impact velocities for either material.

3.4. Fragment Characterization

Post-mortem SEM analysis is carried out on the fracture surfaces of the recovered fragments from the DOP tests at 1078 m/s, and they are shown in
Figure 11, Figure 12, and Figure 13. Shown in Figure 11 (a) is the fracture surface for an S tile impacted at a velocity of 1077 m/s. In Figure 11 (a), a smooth fracture plane is observed, with intragranular fracture being the dominant fracture mode. This corresponds to the cleavage and tearing of the grain layers during fracture. Figure 11 (b) shows another site on the fracture surface, where

⁴³⁵ an example of cleavage fracture in material S is indicated by yellow arrows at the center of the micrograph. Microcracks propagate through the grains with micropores developed in the vicinity of the cracks, and these are indicated by red arrows in Figure 11 (b).

Shown in Figure 11 (c) is the fracture surface for a Z tile impacted at a velocity of 1074 m/s. In contrast to the fracture plane for material S shown in Figure 11 (a), material Z exhibits a much rougher fracture surface. In addition to intragranular fracture and cleavage, porous regions are observed all over the fracture plane. The micropores have lengths ranging from less than 1 µm to 8 µm. The larger pores, with lengths ranging from 12 µm to 23 µm, are likely

⁴⁴⁵ formed by particle pull-out, which have been observed on the fracture surfaces of B₄C-TiB₂ composites before[20]. Figure 11 (d) shows another site on the fracture surface of material Z, where micropores are indicated by yellow arrows and holes left by particle pull-out are indicated by red arrows. It is also observed that micropores and particle pull-outs tend to aggregate at the sites where the
crack density is high. This suggests that pore growth and particle pull-out could
be active actors during an impact event which contribute to a rougher fracture
surface.

Next, EDS is coupled with SEM to further examine the crack growth mechanisms and determine the composition of the secondary phases that appear to ⁴⁵⁵ affect fracture and failure behavior. Figure 12 shows an FESEM micrograph of a fracture plane from material S (Figure 12 (a)) and the corresponding elemental maps of boron (Figure 12 (b)), carbon (Figure 12 (c)), and silicon (Figure 12 (d)). In Figure 12 (a), microcracks are observed to propagate along and through the brighter regions, while the surrounding gray areas are dominated by intra-

- ⁴⁶⁰ granular fracture via grain layer cleavage. In addition, small white inclusions are distributed sparsely over the field of view and usually appear at the grain boundaries, but they do not seem to contribute to the fracture process as they are not found in the vicinity of cracks. Figure 12 (b) and (c) confirms the elemental composition of the gray and brighter regions as monolithic boron carbide and
- ⁴⁶⁵ carbonaceous inclusions, respectively. In Figure 12 (c), the carbon-rich regions have flake-like shapes, while the microcracks tend to grow along the elongated side of the flake. Figure 12 (c) shows that the sparsely distributed white inclusions are silicon-rich, which could be the undissolved residue of the sintering aids. Three major conclusions can be drawn from this figure: (1) microcracks
- ⁴⁷⁰ initiate and grow mostly from the carbonaceous inclusions, which acts as a weak link in the material; (2) no additional secondary phases are detected in material S; (3) silicon-rich inclusions are likely the undissolved residue of the sintering aids used to densify the material[71]. They are grain boundary features and do not appear to contribute to the fracture process.
- In comparison, Figure 13 shows an FESEM micrograph of a fracture plane from material Z (Figure 13 (a)) and the corresponding elemental maps of boron (Figure 13 (b)), carbon (Figure 13 (c)), silicon (Figure 13 (d), and titanium (Figure 13 (e)). Figure 13 (a) shows a triple junction of microcracks, where particle pull-outs, micropores, and secondary phases (distinguished by their

- ⁴⁵⁰ brighter colors) are observed in the vicinity of the junction. The boron element map (Figure 13 (b)) shows that the microcracks pass through the monolithic boron carbide phase, but with multiple discontinuous regions (i.e., absence of boron). The absence of boron constitutes a large portion of the field of view, indicating a large amount of secondary phases existed in the material, especially
- ⁴⁸⁵ at the fracture sites. Figure 13 (c) and (d) confirm this observation, as significant amounts of carbon and silicon occupy the void spaces in Figure 13 (b). The carbonaceous inclusions in Figure 13 (c) do not appear as flake-like as in Figure 12 (c), and they are not the sole propagating sites for the microcracks. Comparing to the sparsely distributed silicon-rich inclusions in Figure 12 (d),
- the silicon-rich regions in Figure 13 (d) appear in bulk in material Z. While a silicon peak was not detected in the XRD spectrum for material Z, the silicon-rich phase is found in significant quantities in the vicinity of microcracks on the fracture surface. This suggests that the silicon-rich phase is not evenly distributed throughout the material and can be a potential facilitator of crack growth. In
- ⁴⁹⁵ addition, Figure 13 (e) shows two regions with highly concentrated titanium. Coupling this with the boron map and the XRD spectrum in Figure 3, it is evident that these two titanium-rich regions correspond to the titanium diboride (TiB₂). The propagation of the microcrack through the TiB₂ phase likely indicates a breakage of the TiB₂ particle cluster during fracture. This additional
- ⁵⁰⁰ phase, combined with the bulk silicon-rich regions and carbonaceous inclusions, creates a more complicated fracture surface and denser microcrack networks in material Z than material S.

4. Discussion

4.1. Microstructural Effects on Material Behavior

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In this study, the elastic modulus and compressive strength were found to be lower in material Z than in material S (Figure 6) while the Vicker's hardness was found to be comparable in both materials. Past studies have found the elastic modulus to increase with increasing TiB_2 content in well consolidated B_4C - TiB_2 composites [15, 72]. However, as shown by the intact surface in Figure 4,

- there is a significant level of porosity in material Z, which is known to degrade the elastic modulus and compressive strength of ceramics[73, 74]. In addition, the presence of silicon impurities may also play a role in the fracture process and reduced compressive strength of material Z. While residual silicon was also found in material S, it is sparsely distributed and largely present within the
- ⁵¹⁵ grain boundaries, as shown in Figure 12. This silicon was not found in greater quantities on the fracture surface or near microcracks, so it is not expected to contribute to the fracture process under loading. In contrast, the silicon secondary phase in material Z is present in both localized and bulk amounts. Analysis of the fracture surfaces on ballistic fragments in Figure 13 showed high
- ⁵²⁰ concentrations of silicon content in the vicinity of microcracks. This suggests that the localized distribution of a silicon-rich phase creates potential sites for crack propagation and weakens material Z. Better performance may be achieved if the silicon content can be dispersed more evenly.

4.2. Ballistic Performance

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The ballistic performance of ceramics in DOP tests is commonly quantified using the ballistic efficiency defined by Rosenberg et al.[34] as:

Ballistic Efficiency =
$$\frac{\rho_b \times (P_0 - P_r)}{\rho_c \times t}$$
 (1)

where t is the tile thickness, ρ_c is the ceramic density, P_r is the residual depth of penetration in the backing after the ceramic has been perforated, and P_0 is the reference depth of penetration in the bare backing material. In order to account for the effect of the backing material, Savio et al.[75] proposed the normalized ballistic efficiency factor (NBE), defined as:

$$NBE = \frac{100}{\rho_c \times t} \times \left(1 - \frac{P_r}{P_0}\right)$$
(2)

In this definition, the residual DOP is normalized by the reference DOP, which has been shown to account for differences in backing material properties [75].

The NBE is preferred over the ballistic efficiency defined by Rosenberg[34] as it enables a comparison between tests performed with different backing materials in the literature.

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Figure 14 shows the NBE for material S and Z plotted against projectile velocity. NBE values calculated based on DOP data from other studies [31, 42, 75, 76] involving boron carbide are also included for comparison. Note that the referenced studies all used 7.62 mm AP projectiles with steel cores, and 540 only results with ceramic tile thicknesses ranging from 5 to 7 mm were included in the figure. Both hot-pressed and reaction bonded boron carbide have been included for completeness. From Figure 14, it can be seen that NBE generally decreases with increasing impact velocity, though this decrease appears to be less sensitive at higher velocities. Taking into account the higher impact velocities in this study, the NBE of material S compares well with the hot-pressed B_4C tested in other studies. For material Z, the NBE near velocities of 932 m/s is comparable to that of material S within scatter and follows the general trend of the hot-pressed B_4C . However, near velocities of 1078 m/s, the NBE for material Z is clearly lower than that of material S. 550

The inferior ballistic performance of material Z at the higher impact velocity may be related to it's mechanical properties and fracture characteristics. A high elastic modulus is thought to extend dwell time during impact[77], so the higher elastic modulus of S tiles may contribute to a longer dwell phase when compared to Z tiles and lead to superior ballistic performance. During the penetration phase, the relatively low compressive strength of material Z may reduce the resistance encountered by the projectile as compared to material S, resulting in a greater DOP in Z. Based on the impact craters shown in Figure 10, it can be seen that the damage is also more localized in the Z tiles than the S tiles, as Z

tiles show smaller impact craters and fewer radial cracks than S tiles. Material S also showed finer fragments than material Z. Therefore, material S may be more efficient at dissipating the kinetic energy of the projectile through the fragmentation and ejection of a larger portion of the ceramic tile than material Z.

Lastly, it is of interest to note that the density of material Z is nearly identical to that of material S. Depending on the percentage of TiB₂ content, the density of B_4C -Ti B_2 composites typically range from 2.53 to 3.30 g/cm³[15, 18, 22, 23]. In material Z, the increase in density due to TiB_2 content is largely offset by the introduction of porosity. This has allowed material Z to retain a comparative

density to material S at the cost of degraded mechanical properties and ballis-570 tic performance. Nonetheless, material Z has shown comparable performance to material S at 932 m/s, and more tests at lower projectile velocities may show that it is a viable alternative to hot-pressed B₄C for these velocities. In developing alternative armor materials, it is important to consider whether a decrease in ballistic performance is worth the weight and cost savings. 575

5. Conclusion

This study compared the microstructure, rate-dependent compressive behavior, and ballistic performance of a pressureless sintered B₄C-TiB₂ composite (material Z) and a hot-pressed B_4C ceramic (material S). The compressive strength of material Z was found to be lower than that of material S through 580 the range of strain rates accessed using quasi-static and dynamic compression experiments. Depth of penetration testing conducted using 7.62 mm AP M2 projectiles showed the two materials to be comparable at an impact velocity of 932 m/s while material S was superior to material Z at a higher impact velocity of 1078 m/s. Post-mortem SEM analysis of ballistic fragments revealed that 585

- the fracture surface of material Z is characterized by intragranular fracture, higher levels of porosity, and localized distributions of a silicon-rich secondary phase. In contrast, the fracture surface of material S is relatively smooth and dominated by intragranular fracture. The inferior compressive properties and
- ballistic performance of material Z are attributed to the level of porosity and 590 uneven distribution of silicon impurities in the microstructure. Tailoring the microstructure of material Z to achieve a comparable density to material S and the use of sintering additives can result in tradeoffs in performance and strength.

These tradeoffs need to be considered in the development of improved armor ⁵⁹⁵ ceramics.

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610 7. Data Availability

The raw/processed data required to reproduce these findings cannot be shared at this time as the data also forms part of an ongoing study.

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930 8. Figures



Figure 1: Average axial strain profiles from uniaxial compression experiments on material S at three dynamic strain rates. For specimen S-B₄C 02, the stress profile computed using the transmitted gauge and the local strain profiles computed from different areas of interest (AOI) are matched in time and plotted along with the average strain. The different AOI's that the local strain profiles are computed from are shown in the inset. The average strain was calculated by averaging across the entire surface.



Figure 2: Schematic of the ballistic testing setup. The ceramic tile to be tested is mounted to a polycarbonate backing, which is used for DOP measurements. Light screens are used to trigger the cameras during the impact event. Two mirrors are used to allow the Shimadzu HPV-X to image the front and side views of the impact. Longer timescale events are captured from the a side view using the Photron FASTCAM SA-Z. This diagram is not to scale.



Figure 3: $\theta - 2\theta$ X-ray diffraction spectrum of (a) Material S and (b) Material Z showing the phase composition of the materials. Note that Material Z contains a significant amount of TiB₂ phase, while a trace amount of Fe₁₃Co₃ is also identified.



Figure 4: SEM micrograph of the mechanically polished surfaces for (a) material S and (b) material Z. The bright regions correspond to boron carbide and the dark regions correspond to various secondary phases in both materials. Yellow markings indicate the nanoindentation locations.



Figure 5: Representative stress strain curves for material S (red) and Z (blue) at a quasi-static strain rate and three dynamic strain rates.



Figure 6: Peak stress plotted as a function of strain rate for material S (red) and Z (blue). The strain rate axis is in logarithmic scale.



Figure 7: Depth of penetration (DOP) results for material S (red) and Z (blue) as a function of projectile velocity. The reference DOP obtained by impacting the bare polycarbonate backing is also included for comparison.



Figure 8: High-speed frames of the impact event captured at 2,000,000 FPS using the Shimadzu HPV-X are shown for S (left) and Z (right). Both targets were impacted at \sim 1078 m/s. Within each frame, the front view is shown on the left and the side view, captured using the reflection from a mirror, is shown on the right. The first frame is the first frame in which the projectile contacts the tile, and this is defined as 0 µs. The time stamps of the subsequent frames reflect the time that has elapsed since contact.



Figure 9: High-speed frames of the impact event captured at 40,000 FPS using a Photron FASTCAM SA-Z are shown for S (left) and Z (right). Both targets were impacted at ~932 m/s. The first frame is the first frame in which the projectile contacts the tile, and this is defined as $0 \,\mu s$. The time stamps of the subsequent frames reflect the time that has elapsed since contact. These frames capture the evolution of fragment sizes after the impact event.



Figure 10: Post-impact view of perforated S tiles impacted at (a) 929 m/s and (b) 1079 m/s, and Z tiles impacted at (c) 928 m/s and (d) 1075 m/s. The dark material at the centre of the craters is melted polycarbonate that flowed out of the perforation after the DOP experiments.



Figure 11: (a - b) Fractography of the monolithic B_4C (material S) showing smooth fracture planes. Intragranular fracture corresponding to grain layer tearing is identified by yellow arrows and micropres are indicated by red arrows. (c - d) Fractography of the B_4C -TiB₂ composite (material Z) showing rough fracture planes. A mixed mode of fracture, including intragranular, intergranular, and particle pull-out are observed. Micropores are indicated by yellow arrows and particle pull-out is indicated by red arrows.



Figure 12: FESEM coupled with EDS investigation on a magnified view of material S. The fracture plane surrounding these inclusion-induced cracks remains smooth and dominated by intragranular fracture. (a) FESEM micrograph showing crack growth along the carbonaceous inclusions. EDS maps for (b) boron, (c) carbon, (d) silicon, and (e) titanium are shown.



Figure 13: FESEM coupled with EDS investigation on a magnified view of material Z. A mixed mode of fracture mechanisms is observed. (a) FESEM micrograph showing a triple junction formed by crack interaction. Pull-outs from the secondary phases and micropores are located in the vicinity of the cracks. (b) EDS map of the boron element. (c) EDS map of the carbon element. (d) EDS map of the silicon element.



Figure 14: Normalize ballistic efficiency (NBE) for material S and Z compared against NBE of boron carbide tested at different velocities from other studies[31, 42, 75, 76].

9. Tables

Table 1: Pulse snaping configurations used in dynamic experiments					
Strain Data (a ⁻¹)		Pulse Shape	Strikon Longth (mm)		
Strain Rate (s)	Material	Diameter (mm)	Thickness (mm)	Striker Length (mm)	
620 to 1100	HDPE	3.18	2.38	152	
260 to 560	HDPE	3.18	1.59	304	
185 to 245	Tin	3.97	1.00	304	

Table 1: Pulse shaping configurations used in dynamic experiments

Table 2: Nanoindentation and Vicker's hardness res	ults
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Matarial	Nanoindenta	tion Hardness (GPa)	Vielen's Handrags (CDs)	
Material	Bright	Dark	vicker's hardness (GPa)	
$S(B_4C)$	40.3 ± 1.4	34.6 ± 8.9	35.4 ± 1.5	
$Z~(B_4C\text{-}TiB_2)$	40.5 ± 1.6	24.6 ± 7.3	35.4 ± 2.0	

Table 3: Depth of penetration measurements for material S and Z

Material	Density	Tile Thickness	Projectile Velocity	Residual Penetration	Reference Penetration
	(g/cm^3)	(mm)	(m/s)	(mm)	(mm)
$S(B_4C)$	2.49	6.45	929	45	220.7
$S(B_4C)$	2.50	6.38	936	50.2	220.7
$S(B_4C)$	2.50	6.40	1079	53	286.2
$S(B_4C)$	2.49	6.40	1078	85	286.2
$S(B_4C)$	2.49	6.43	1081	82	286.2
$Z~(B_4C\text{-}TiB_2)$	2.54	6.17	928	63	220.7
$Z (B_4C\text{-}TiB_2)$	2.52	6.22	939	89	220.7
$Z~(B_4C\text{-}TiB_2)$	2.55	6.10	945	51.8	220.7
$Z~(B_4C\text{-}TiB_2)$	2.53	6.15	1075	126	286.2
$Z~(B_4C\text{-}TiB_2)$	2.52	6.15	1075	117	286.2
$Z \; (B_4 C\text{-}TiB_2)$	2.55	6.12	1082	133	286.2